

University of Wollongong

Research Online

Faculty of Engineering and Information
Sciences - Papers: Part B

Faculty of Engineering and Information
Sciences

2019

Correlation Between Crystal Rotation and Redundant Shear Strain in Rolled Single Crystals: A Crystal Plasticity FE Analysis

Hui Wang

University of Wollongong, huiw@uow.edu.au

Cheng Lu

University of Wollongong, chenglu@uow.edu.au

Anh Kiet Tieu

University of Wollongong, ktieu@uow.edu.au

Yu Liu

University of Wollongong, yl751@uowmail.edu.au

Rui Wang

University of Wollongong, rw985@uowmail.edu.au

See next page for additional authors

Follow this and additional works at: <https://ro.uow.edu.au/eispapers1>



Part of the [Engineering Commons](#), and the [Science and Technology Studies Commons](#)

Recommended Citation

Wang, Hui; Lu, Cheng; Tieu, Anh Kiet; Liu, Yu; Wang, Rui; and Li, Jintao, "Correlation Between Crystal Rotation and Redundant Shear Strain in Rolled Single Crystals: A Crystal Plasticity FE Analysis" (2019).

Faculty of Engineering and Information Sciences - Papers: Part B. 2666.

<https://ro.uow.edu.au/eispapers1/2666>

Research Online is the open access institutional repository for the University of Wollongong. For further information contact the UOW Library: research-pubs@uow.edu.au

Correlation Between Crystal Rotation and Redundant Shear Strain in Rolled Single Crystals: A Crystal Plasticity FE Analysis

Abstract

The correlation between crystal rotation and redundant shear strain in rolled single crystals was investigated by using the crystal plasticity finite element (CPFE) model in this paper. The deformation in aluminium single crystals of four representative orientations (rotated-Cube, Goss, Copper, and Brass) after rolling and plain strain compression was simulated, and the predictions have been validated by the experimental observations. In the rotated-Cube and Goss, the redundant shear strain and crystal rotation were in the same pattern, alternating along the thickness, while the relation between them was not obvious for the Copper and Brass due to their asymmetrical distributions of activated slip systems. The relations between slip system activation, crystal rotation, and shear strain were investigated based on the CPFE model, and the correlation between shear strain and crystal rotation has been built.

Disciplines

Engineering | Science and Technology Studies

Publication Details

Wang, H., Lu, C., Tieu, K., Liu, Y., Wang, R. & Li, J. (2019). Correlation Between Crystal Rotation and Redundant Shear Strain in Rolled Single Crystals: A Crystal Plasticity FE Analysis. *Acta Metallurgica Sinica (English Letters)*, 32 (4), 452-460.

Authors

Hui Wang, Cheng Lu, Anh Kiet Tieu, Yu Liu, Rui Wang, and Jintao Li

Correlation between crystal rotation and redundant shear strain in rolled single crystals: a crystal plasticity FE analysis

Hui Wang*, Cheng Lu, Kiet Tieu, Yu Liu, Rui Wang, Jintao Li

School of Mechanical, Materials and Mechatronic Engineering, University of Wollongong, New South Wales 2522, Australia

*Corresponding author. Dr. Hui Wang, Tel: +61 2 42214639. E-mail address: hw737@uowmail.edu.au.

Abstract: The correlation between crystal rotation and redundant shear strain in rolled single crystals was investigated by using the crystal plasticity finite element (CPFE) model in this paper. The deformation in aluminium single crystals of four representative orientations (rotated-Cube, Goss, Copper, and Brass) after rolling and plain strain compression was simulated, and the predictions have been validated by the experimental observations. In the rotated-Cube and Goss, the redundant shear strain and crystal rotation were in the same pattern, alternating along the thickness, while the relation between them was not obvious for the Copper and Brass due to their asymmetrical distributions of activated slip systems. The relations between slip system activation, crystal rotation, and shear strain were investigated based on the CPFE model, and the correlation between shear strain and crystal rotation has been built.

Keywords: Crystal plasticity finite element (FE); Single crystal; Crystal rotation; Shear strain; Orientation stability

1. Introduction

The deformation behaviours in single crystals after rolling and plain strain compression (PSC) have been extensively investigated (e.g., [1-7]). It has been found that the crystal rotation is

very low in single crystals having stable orientations, including Copper $\{112\}\langle 111\rangle$ [1], Goss $\{011\}\langle 100\rangle$ [2, 3], and Brass $\{011\}\langle 211\rangle$ [4], while it is large in unstable orientations, such as Cube $\{001\}\langle 100\rangle$ [5] and rotated-Cube (roCube) $\{001\}\langle 110\rangle$ [6, 7]. An alternating pattern '+ - + -' of crystal rotation along the thickness has been found in rolled Cube [8] and roCube [6], in which the four activated slip systems are symmetrically distributed about the rolling direction (RD)-transverse direction (TD) plane, and RD-normal direction (ND) plane. In contrast, the through-thickness crystal rotation does not exhibit any symmetry about the mid-thickness in single crystals that have asymmetrically distributed slip systems [1, 4]. As for shear strain, it is surprising that it is also in the '+ - + -' pattern in Cube [9], which was experimentally measured by the embedded-pin method. However, the correlation between crystal rotation and shear strain in other orientations has not been observed, since measuring the redundant shear strain in single crystals is challenging [9].

As an alternative to experimental methods, texture modelling has become a powerful tool to study plastic deformation and texture evolution, and various crystal plasticity models have been developed. Homogenization at different levels has been adopted in the Taylor model, ALAMEL model, and self-consistent model [10]. Different from these models, no homogenization is assumed in the crystal plasticity finite element (CPFE) model, and thus this model is in principle regarded as the best one in predicting plastic deformation and texture evolution [11, 12]. The CPFE model incorporates the crystal plasticity constitutive model into the finite element (FE) framework, where the FE framework serves as the solver of boundary problems and the crystal plasticity constitutive law is taken into account at each integration point [13]. The equilibrium of stress and strain is achieved by the basic principles of mechanics at the same time for all material points [10]. The deformation in

each element is determined by its current properties (e.g., crystal orientation) and external constraints (e.g., stress, strain). After an FE increment, the material properties are updated and used in the next increment. In this way, texture evolution and plastic deformation are fully coupled. According to the reports [14, 15], the main advantage of the CPFEM model is its ability to solve crystal plasticity problems (e.g., slip system activation, texture evolution, and plastic deformation) under complicated internal and external boundary conditions.

In the authors' CPFEM simulations of rolled single crystals, the crystal rotation has been found to be related to the redundant shear strain. The aim of this report is to study how they are correlated. The deformation in aluminium single crystals with four representative orientations (roCube, Goss, Copper, and Brass) has been predicted by the CPFEM model. The slip system activation, shear strain, and crystal rotation have been investigated, and the relation between them was studied.

2. Simulation conditions and texture modelling

Table 1 Simulation conditions of four simulation cases.

	Case A	Case B	Case C	Case D
Initial orientation	roCube(00 $\bar{1}$)[110]	Goss (011)[100]	Copper (112)[11 $\bar{1}$]	Brass ($\bar{1}$ 01)[1 $\bar{2}$ 1]
Orientation stability	Unstable	Stable	Semi-stable	Stable
Activated slip systems	Symmetrical	Symmetrical	Asymmetrical	Asymmetrical
Deformation	Rolling	Rolling	Rolling	PSC
Reduction	50%	30%	50%	43%
Friction coefficient	0.25	0.25	0.11	0.1
Diameter of rolls	75 mm	75 mm	310 mm	∞
Initial thickness	3.0 mm	2.8 mm	4.0 mm	7.0 mm
Reference	[6]	[3]	[16]	[4]

Four simulation cases of rolling and PSC were carried out, as listed in Table 1, and the simulations were designed to match the experiment conditions. Case A, B, and C were deformed by rolling (Fig.1a) and 2D models (plain strain conditions) were used, since the

main deformation was on the RD-ND plane. A 3D model was developed for the PSC in case D (Fig.1b), since it is able to measure the shear strain on the RD-TD plane. The rolls in rolling (or dies in PSC) were considered as analytical rigid bodies and the diameters are shown in Table 1. The friction between the sheet and rolls was described by the Coulomb's friction law and the friction coefficients were selected after testing various ones, since they generated the best-matched predicted textures. It was 0.25 for the unlubricated rolling in case A and B, 0.11 for the lubricated rolling in case C, and 0.1 for the improved lubrication conditions in case D. The coefficients of 0.25 and 0.11 match the suggested values for unlubricated and lubricated rolling [17], respectively. The element type was CPE4R in 2D models and C3D8R in the 3D model, which can provide an efficient and fast numerical formulation. Enhanced hourglass control was used to increase the resistance to the hourglassing problem and provide more accurate displacement solutions. The number of elements was determined by finding the element size at which the mechanical response became independent of the mesh resolution.

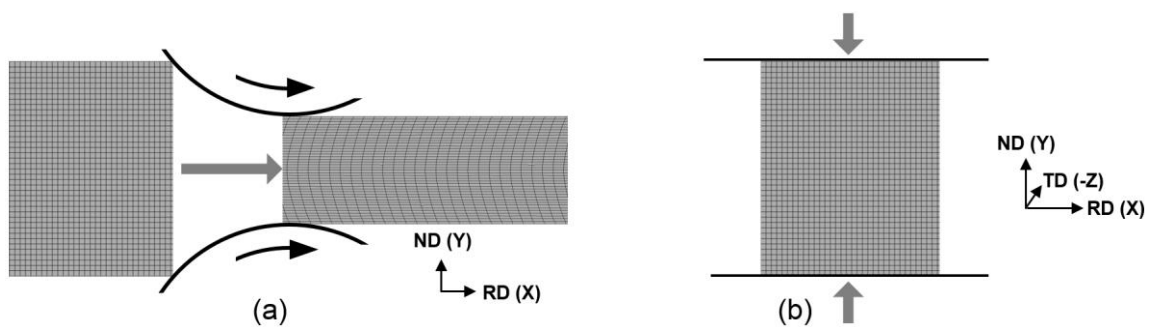


Fig.1. (a) Rolling, and (b) PSC model.

The starting materials were pure aluminium single crystals with initial orientations of roCube $\{001\}\langle 100\rangle$ [6], Goss $\{011\}\langle 100\rangle$ [3], Copper $\{112\}\langle 111\rangle$ [16], and Brass $\{011\}\langle 211\rangle$ [4]. $\{001\}\langle 100\rangle$ is an unstable orientation in rolling, and its four potentially activated slip

systems are shown in Fig.2a. Fig.2b shows the distribution of slip systems of Goss, a stable orientation. Copper is regarded as a semi-stable orientation in this study, since its crystal rotation after rolling is not small. Its four slip systems are symmetrical about the RD-ND plane, but not about the RD-TD plane (Fig.2c). Brass is a stable orientation and its two slip systems are neither symmetrical about the RD-ND plane nor the TD-ND plane (Fig.2d).

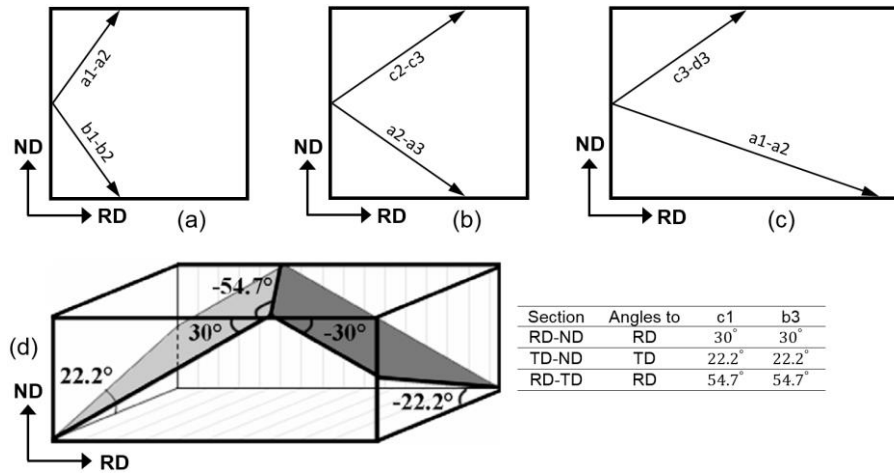


Fig.2. Distribution of activated slip systems in (a) roCube, (b) Goss, (c) Copper, and (d) Brass [18].

The kinematical scheme of the crystal plasticity model developed by Asaro [19, 20] was adopted in the present study, which has been widely used and recognized. A rate-dependent hardening model, Bassani-Wu hardening model [21, 22], was used, since it could accurately describe the material hardening [23]. In this hardening model, the shear strain rate $\dot{\gamma}^{(\alpha)}$ on slip system α is determined by its resolved shear stress $\tau^{(\alpha)}$, as described by Eq. (1), where $\dot{\gamma}_0^{(\alpha)}$ is the reference value of the shear strain rate, $\tau_c^{(\alpha)}$ is the critical resolved shear stress, and n is the rate-sensitive exponent of slip system α . The values of $\dot{\gamma}_0^{(\alpha)}$, n and $\tau_c^{(\alpha)}$ are given in Table 2.

$$\dot{\gamma}^{(\alpha)} = \dot{\gamma}_0^{(\alpha)} \operatorname{sgn}(\tau^{(\alpha)}) \left| \frac{\tau^{(\alpha)}}{\tau_c^{(\alpha)}} \right|^n \quad \text{for } \tau^{(\alpha)} \geq \tau_c^{(\alpha)} \quad (1a)$$

$$\dot{\gamma}^{(\alpha)} = 0 \quad \text{for } \tau^{(\alpha)} < \tau_c^{(\alpha)} \quad (1b)$$

$$\text{sgn}(x) = \begin{cases} 1 & \text{for } x \geq 0 \\ -1 & \text{for } x < 0 \end{cases} \quad (1c)$$

The $\tau_c^{(\alpha)}$ is the strength of activation of slip systems, and it increases with increasing strain according to

$$\dot{\tau}_c^{(\alpha)} = \sum_{\beta=1}^N h_{\alpha\beta} |\dot{\gamma}^{(\beta)}| \quad (2)$$

where $h_{\alpha\beta}$ is the hardening modulus. It is self-hardening, i.e., $h_{\alpha\alpha}$, when α is equal to β , while it is latent hardening $h_{\alpha\beta}$ when α is not equal to β . The $h_{\alpha\alpha}$ and $h_{\alpha\beta}$ are expressed by:

$$h_{\alpha\alpha} = \left[(h_0 - h_s) \text{sech}^2 \left(\frac{(h_0 - h_s) \gamma^{(\alpha)}}{\tau_1 - \tau_0} \right) + h_s \right] \left[1 + \sum_{\substack{\beta=1 \\ \beta \neq \alpha}}^N f_{\alpha\beta} \tanh \left(\frac{\gamma^{(\beta)}}{\gamma_0} \right) \right] \quad \text{for } \alpha = \beta \quad (3a)$$

$$h_{\alpha\beta} = q h_{\alpha\alpha} \quad \text{for } \alpha \neq \beta \quad (3b)$$

where h_0 is the hardening modulus after initial yield, h_s is the hardening modulus of easy slip, τ_1 is the critical stress when plastic flow begins, τ_0 is the initial critical resolved shear stress, q is the ratio between latent hardening modulus and self-hardening modulus, and $f_{\alpha\beta}$ represents the interaction between two slip systems α and β . The value of $f_{\alpha\beta}$ is determined by the relative position of two slip systems. The parameter $f_{\alpha\beta}$ is chosen as: $a_1 = a_2 = a_3 = 1.75$, $a_4 = 2$ and $a_5 = 2.25$ [24]. Other material parameters used in the hardening models were evaluated by fitting the simulated stress–strain curve with the experimental results of an aluminium single crystal under PSC [25], and they are listed in Table 2. Three elastic moduli are $C_{11} = 112,000$ MPa, $C_{12} = 66,000$ MPa and $C_{44} = 28,000$ MPa [26].

Table 2 Parameters used in the Bassani-Wu hardening model.

n	$\dot{\gamma}_0$ (s^{-1})	h_0 (MPa)	h_s (MPa)	τ_1 (MPa)	τ_0 (MPa)	q
300	0.0001	100	0.01	6.3	6	1

The commercial FE code Abaqus/Standard Ver.6.9 was used to carry out the simulations, into which the crystal plasticity model was implemented by the user-defined material (UMAT) subroutine. The materials used in this study were aluminium single crystals of FCC structure, and the slip plane and slip direction were $\{111\}$ and $\langle 110 \rangle$, respectively. The crystal plasticity theory, CPFEM implementation, hardening model, and material parameters have been given in Ref. [12]. The combination of this CPFEM model and the set of material parameters has accurately captured the texture evolution under different processes [12, 27, 28].

3. Results

3.1. Case A: roCube

Following the method used in the corresponding experimental research [6], the crystal rotation relative to the initial orientation was partitioned into TD-, RD-, and ND-rotation. The TD-rotation is strongly dominant over RD- and ND-rotation, and accordingly, only TD-rotation is shown in Fig.3. The predicted through-thickness TD-rotation in Fig.3b matches well with the experimental measurement in Fig.3a [6]. Though the reduction was only 50%, the evolved TD-rotation is very high, with a maximum value of 28° , and thus roCube is regarded as unstable in rolling [6, 9]. The direction of TD-rotation alternates along the thickness and divides the thickness into four matrix bands (M), M1-M2-M1-M2. The TD-rotation is in the positive (clockwise) direction in M1, while it is in the negative (anticlockwise) direction in M2. The denotation of matrix bands in the simulation is slightly different from that in Fig.3a, where the experimentally observed region is noticeably smaller

than the whole thickness [6]. It is surprising that the macroscopic redundant shear strain (γ_{XY}) distributes in the same pattern as TD-rotation, but they are in the opposite direction, since it is $-\gamma_{XY}$ in Fig.3b. The shear strain γ_{XY} is very low in this case considering dry rolling conditions.

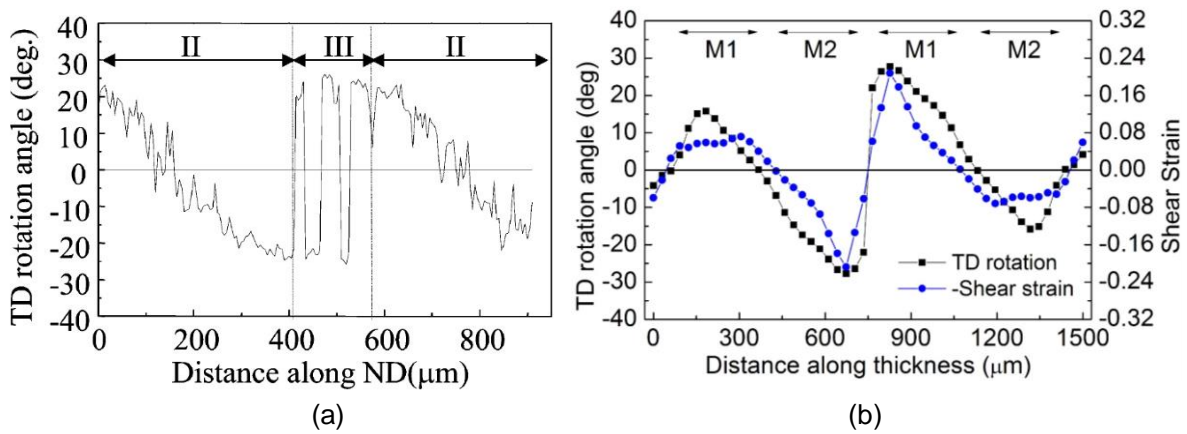


Fig.3. Distribution of (a) TD-rotation in the experiment, and (b) TD-rotation and $-\gamma_{XY}$ in the simulation of roCube after a 50% reduction.

Four slip systems shown in Fig.2a were activated in the roCube, the same as those in the experiment [6], and they are a1 (111)[01 $\bar{1}$], a2 (111)[$\bar{1}$ 01], b1 ($\bar{1}\bar{1}$ 1)[0 $\bar{1}\bar{1}$], and b2 ($\bar{1}\bar{1}$ 1)[101]. The shear strain on a1 (γ_{a1}) is equal to γ_{a2} due to their symmetries (Fig.2a), and it is the same for b1 and b2. Therefore, only γ_{a1} and γ_{b1} are shown in Fig.4a, while Fig.4b represents the imbalance ratio between γ_{a1} and γ_{b1} , $(\gamma_{a1} - \gamma_{b1})/\max(\gamma_{a1}, \gamma_{b1})$. The whole thickness in Fig.4a and b is also divided into four matrix bands, where γ_{b1} is higher than γ_{a1} in M1, while γ_{b1} is lower in M2. The imbalance ratio is in the same direction as shear strain (Fig.3b), and its value is very high, almost 1.0 at some points (near the centre) that possess large TD-rotation.

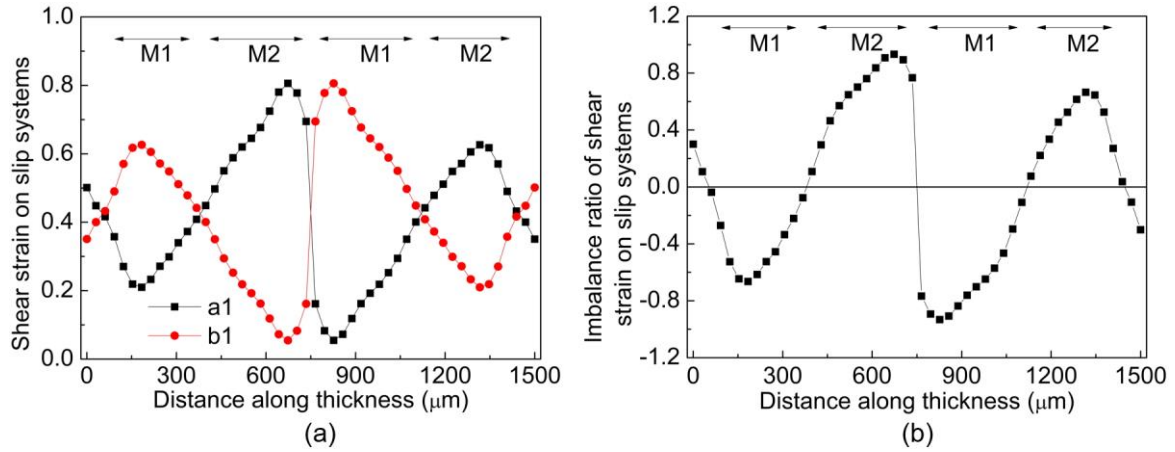


Fig.4. Distribution of (a) shear strain on slip system a1 (γ_{a1}) and b1 (γ_{b1}), and (b) imbalance ratio between γ_{a1} and γ_{b1} , $(\gamma_{a1} - \gamma_{b1}) / \max(\gamma_{a1}, \gamma_{b1})$.

3.2. Case B: Goss

In this case, the partitioned TD-rotation agrees well with the experimental observation [3], as shown in Fig.5. The maximum TD-rotation is only 1.6° , and thus Goss is regarded as stable [2, 3]. Only two matrix bands developed in the Goss, and the TD-rotation is negative and positive in M2 and M1, respectively. The macroscopic shear strain, $-\gamma_{XY}$, is in the same pattern as TD-rotation and its value is also very low (Fig.5b).

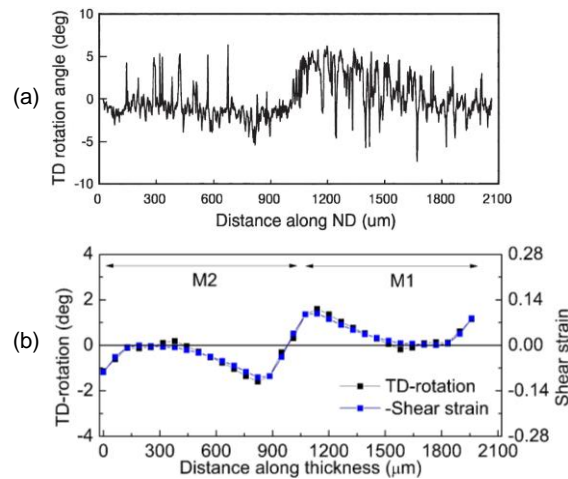


Fig.5. Distribution of (a) TD-rotation in the experiment [3], and (b) TD-rotation and $-\gamma_{XY}$ in the simulation of Goss after a 30% reduction.

The four activated slip systems in the Goss are a2 (111)[$\bar{1}01$], a3 (111)[$1\bar{1}0$], c2 ($\bar{1}11$)[101], and c3 ($\bar{1}11$)[$\bar{1}\bar{1}0$] (Fig.2b). The shear strain on c2 is equal to that on c3, and this is also true for a2 and a3. Only γ_{a2} and γ_{c2} are shown in Fig.6a, and the imbalance ratio calculated according to $(\gamma_{c2} - \gamma_{a2})/\max(\gamma_{c2}, \gamma_{a2})$ is shown in Fig.6b. The activation of slip systems also divides the thickness into two matrix bands, where γ_{c2} is higher than γ_{a2} in M2, while γ_{a2} is dominant over γ_{c2} in M1. Accordingly, the imbalance ratio is positive in M2 (Fig.6b), while negative in M1. The imbalance ratio distributes in a similar pattern to shear strain and TD-rotation in Fig.5b, in the same direction as the former and opposite direction as the latter.

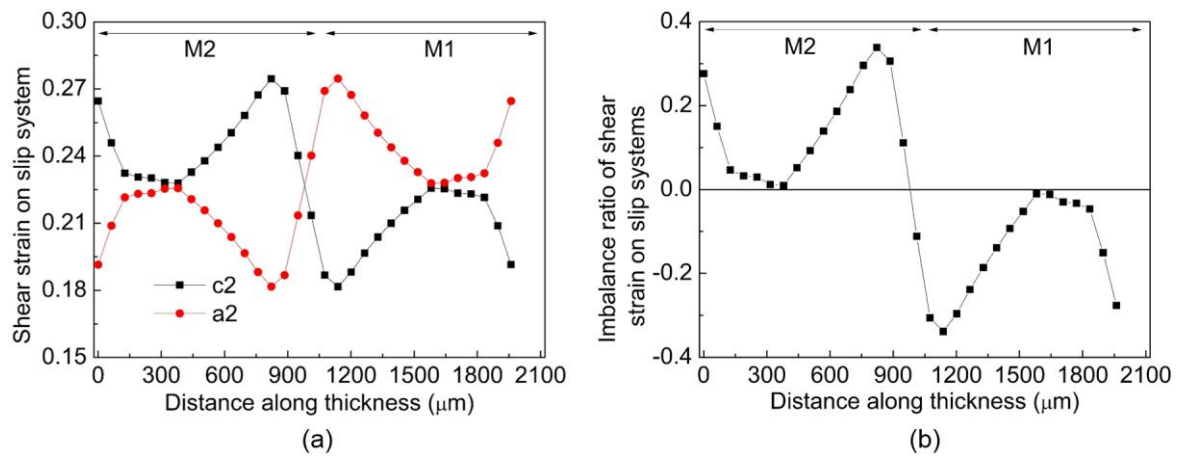


Fig.6. Distribution of (a) shear strain on slip system c2 (γ_{c2}) and a2 (γ_{a2}), and (b) imbalance ratio between γ_{c2} and γ_{a2} , $(\gamma_{c2} - \gamma_{a2})/\max(\gamma_{c2}, \gamma_{a2})$.

3.3. Case C: Copper

The distribution of TD-rotation and shear strain (represented by the deformed FE mesh) shown in Fig.7a is also plotted in Fig.7b. The shear strain is positive along the whole thickness, but its value is almost zero at the lower surface. Like γ_{XY} , the TD-rotation is also not symmetrical about the mid-thickness. The whole thickness is also divided into two matrix bands by the TD-rotation, M1 and M2. The four activated slip systems are a1

(111)[01 $\bar{1}$], a2(111)[$\bar{1}$ 01], c3($\bar{1}$ 11)[$\bar{1}$ $\bar{1}$ 0], and d3($\bar{1}$ $\bar{1}$ 1)[110] (Fig.2c). Slip system a1 and a2 are co-planar, and c3 and d3 are co-directional. The shear strain on a1 and a2 are the same, and γ_{c3} is equal to γ_{d3} . The activation of slip systems further partitions M1 into M1a and M1b (Fig.7c). In M1a, γ_{a1} is higher than γ_{c3} , while γ_{c3} is relatively higher in M1b. This distribution of TD-rotation, shear strain, and slip system activation has been observed in other rolled aluminium single crystals of Copper orientation [16, 29].

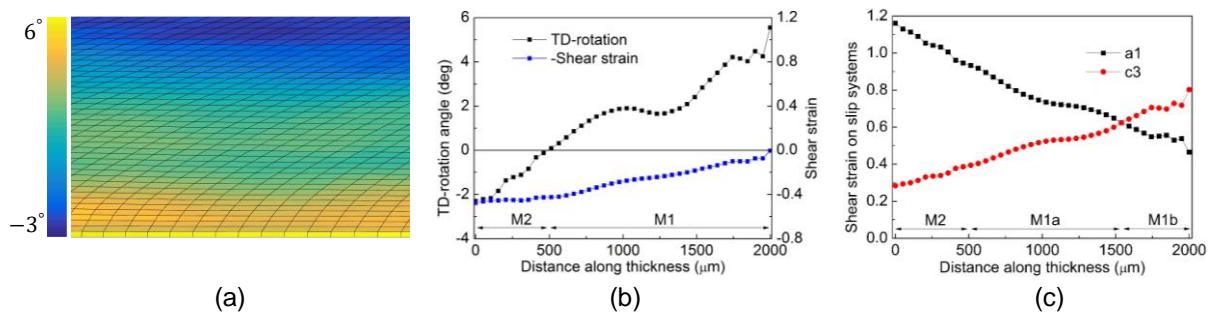


Fig.7. Distribution of (a) TD-rotation and deformed FE mesh, (b) TD-rotation and $-\gamma_{XY}$, and (c) shear strain on slip system a1 (γ_{a1}) and c3 (γ_{c3}) along the thickness.

3.4. Case D: Brass

As for the Brass orientation, a large change in the sample geometry on the RD-TD plane has been revealed in the experiment [4] and simulation (Fig.8), but the deformation is almost uniform within the sample. The shear strain γ_{XZ} is about 0.29 after a 43% reduction. The crystal rotation is very low in the experiment, as expressed by the {1 1 1} pole figures from three regions (Fig.8a). A similar texture was predicted in Fig.8b, where the pole figure was constructed from all elements.

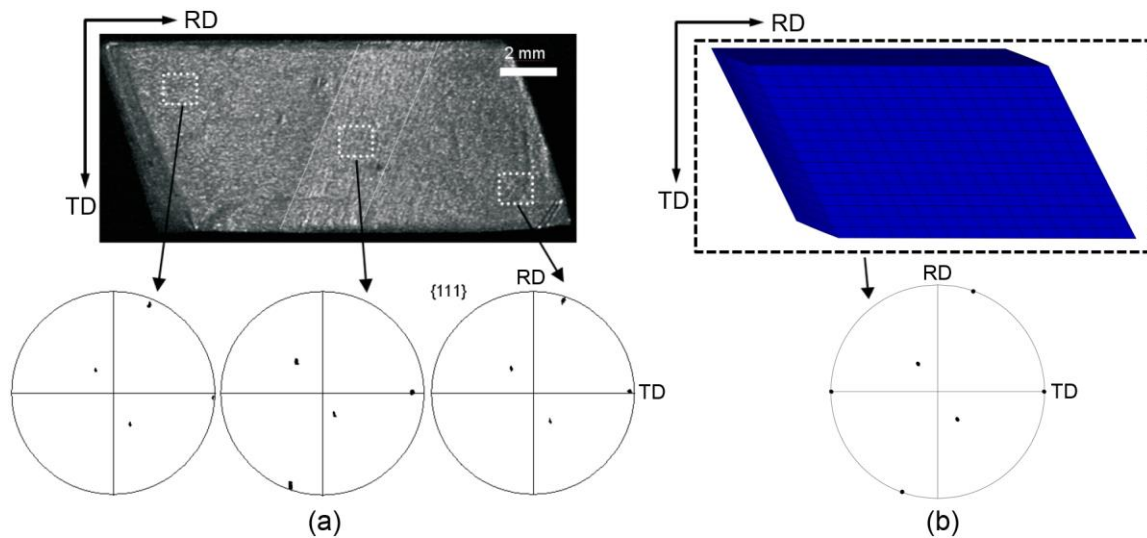


Fig.8. Sample shape changes and $\{111\}$ pole figures in the (a) experiment [4], and (b) simulation.

Only two slip systems, $c1$ ($\bar{1}11$)[$01\bar{1}$] and $b3$ ($\bar{1}\bar{1}1$)[$\bar{1}10$], were activated in the Brass. Fig.9 shows the evolution of shear strain on these two slip systems as a function of deformation time in one representative element. It can be seen that γ_{c1} and γ_{b3} increase gradually with the deformation time.

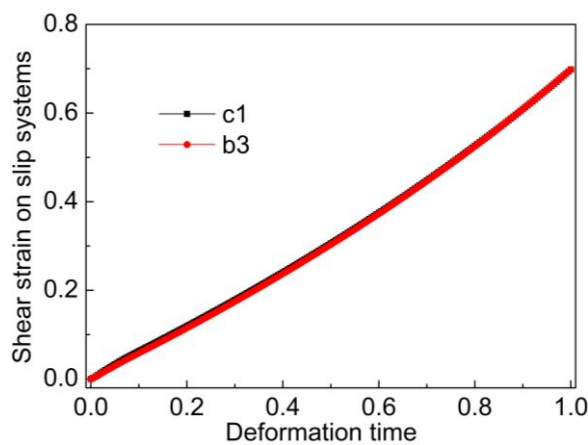


Fig.9. Evolution of shear strain on slip system $c1$ (γ_{c1}) and $b3$ (γ_{b3}) in one representative element.

roCube	M1	$\gamma_{a1-a2} < \gamma_{b1-b2}$	-TD	+TD	-	-TD	$(-)=(-)+(+) , \Omega_{TD}^P > \Omega_{TD}^*$
	M2	$\gamma_{a1-a2} > \gamma_{b1-b2}$	+TD	-TD	+	+TD	$(+)=(+)+(-) , \Omega_{TD}^P > \Omega_{TD}^*$
Goss	M1	$\gamma_{c2-c3} < \gamma_{a2-a3}$	-TD	+TD	-	-TD	$(-)=(-)+(+) , \Omega_{TD}^P > \Omega_{TD}^*$
	M2	$\gamma_{c2-c3} > \gamma_{a2-a3}$	+TD	-TD	+	+TD	$(+)=(+)+(-) , \Omega_{TD}^P > \Omega_{TD}^*$
Copper	M2	$\gamma_{a1-a2} > \gamma_{c3-d3}$	+TD	-TD	+	+TD	$(+)=(+)+(-) , \Omega_{TD}^P > \Omega_{TD}^*$
	M1a	$\gamma_{a1-a2} > \gamma_{c3-d3}$	+TD	+TD	+	+TD	$(+)=(+)+(+) , \Omega_{TD}^P > \Omega_{TD}^*$
	M1b	$\gamma_{a1-a2} < \gamma_{c3-d3}$	-TD	+TD	+	+TD	$(+)=(-)+(+) , \Omega_{TD}^P < \Omega_{TD}^*$

In the roCube, the slip system set a1-a2 produced plastic spin about TD (Ω_{TD}^P) in the positive direction according to Eq. (5), while the d1-d2 set caused negative Ω_{TD}^P . The Ω_{TD}^P induced by γ_{a1-a2} was partially or completely compensated by γ_{b1-b2} . The compensation is complete when γ_{a1-a2} is equal to γ_{b1-b2} , and this can be found at the boundaries of adjacent matrix bands (Fig.4b), i.e., imbalance ratio being zero. Imbalance between γ_{a1-a2} and γ_{b1-b2} exists in matrix bands (Fig.4 and Table 3), in which the compensation is partial. Due to the mutual compensation between slip system sets, the plastic spin is usually small when multi-slip occurs [12]. In M1, γ_{b1-b2} is much higher than γ_{a1-a2} , and the compensation resulted in large negative Ω_{TD}^P . The total material spin (Ω_{TD}) represented by the shear strain (γ_{XY}) is negatively low (Fig.3b). Therefore, positive lattice spin (Ω_{TD}^*) was required to meet the deformation according to Eq. (4). Though large Ω_{TD}^* evolved in the roCube, it is still lower than Ω_{TD}^P (Table 3). Therefore, the shear strain is in the opposite direction to TD-rotation. This is how the redundant shear strain and TD-rotation are correlated. In M2, positive Ω_{TD}^P was produced by γ_{a1-a2} after being partially compensated by γ_{b1-b2} , and negative Ω_{TD}^* developed to meet the material spin Ω_{TD} (Table 3). The similar deformation behaviour was also observed in the Goss. The slip system set a2-a3 and c2-c3 produced positive and negative Ω_{TD}^P , respectively. In M1, γ_{a2-a3} is higher than γ_{c2-c3} , so negative Ω_{TD}^P was produced after their opposite contributions. According to Eq. (4), positive Ω_{TD}^* was required to meet the negative Ω_{TD} . In contrast, Ω_{TD}^P , Ω_{TD}^* , and Ω_{TD} in M2 are positive, negative, and

positive, respectively. Similar to that in the roCube, the redundant shear strain is in the opposite direction to TD-rotation. In case C, the activation of a1-a2 caused positive Ω_{TD}^P , and c3-d3 resulted in negative Ω_{TD}^P . In M2, the redundant Ω_{TD}^P after the compensation is positively large due to the large difference between γ_{a1-a2} and γ_{c3-d3} , and negative Ω_{TD}^* developed to accommodate Ω_{TD} . In this matrix band, Ω_{TD}^P is larger than Ω_{TD}^* (Table 3), so TD-rotation and shear strain are in the opposite direction. Ω_{TD}^P became smaller in M1a due to the decreased difference between γ_{a1-a2} and γ_{c3-d3} , and low positive Ω_{TD}^* evolved to meet the positive Ω_{TD} . In M1b, negative Ω_{TD}^P developed, since γ_{a1-a2} is lower than γ_{c3-d3} . Large positive Ω_{TD}^* developed to accommodate the positive Ω_{TD} . Ω_{TD}^* is higher than Ω_{TD}^P in M1b (Table 3), so shear strain and TD-rotation are in the same direction. In the Brass, the same activated slip systems having the same magnitude of shear strain is the reason for the uniform deformation in the whole sample. The large change in the sample geometry is caused by the crystal slip, which is not reduced by the lattice spin.

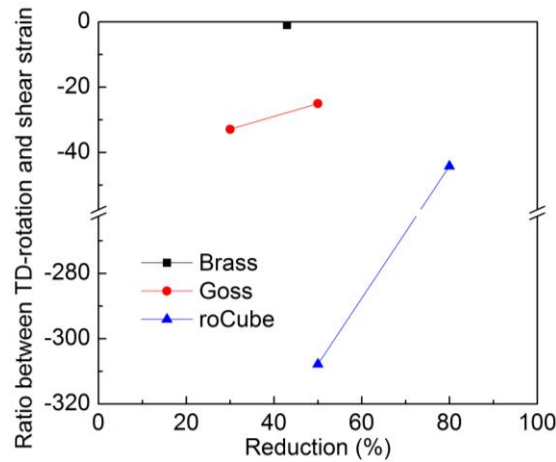


Fig.10. Ratios between crystal rotation and redundant shear strain.

The correlation between crystal rotation and shear strain has not been extensively studied. A plasticity analysis was performed to study the correlation in Cube and Goss [3], in which a shear strain imbalance between the two sets of slip systems was introduced to generate the

'+ - + -' pattern, but the value of imbalance shear strain has not been validated. In contrast, the imbalance shear strain between slip system sets was accurately calculated in this study, and the imbalance ratio varies along the thickness (e.g., in Fig.4b and Fig.6b). The alternate slip system activation along the thickness is due to the influence of shear stress, since the shear stress would cause an imbalance of resolved shear stress between the two sets of slip systems. The shear stress is due to the combined effect of rolling bite geometry and surface friction [33, 34]. The slip systems in the roCube are more sensitive to the shear stress due to their large inclination, which means a large difference in the resolved shear stress on slip systems between a1-a2 and b1-b2 is expected, and consequently the imbalance ratio in Fig.4b varies greatly. In contrast, the inclination of the activated slip systems in the Goss is comparatively low (Fig.2b), and thus the influence of shear stress to the resolved shear stress on slip systems is limited [30], so the shear strain on a2-a3 is close to γ_{c2-c3} . Besides, the plastic spin is also influenced by the slip system direction according to Eq. (5), where the change in slip system direction due to crystal rotation is not considered in the plasticity analysis in Ref. [3]. The shear strain on slip systems increases almost linearly with deformation time (Fig.9) due to no crystal rotation. The plastic spin in the Goss would be higher than that in the roCube if the activated slip systems in them are of the same shear strain. Similarly, the plastic spin would be even less in the Copper, and this is why the plastic spin is lower than lattice spin in M1b. Fig.10 shows the ratio between increase of TD-rotation and shear strain as a function of reduction in the Brass, Goss and roCube. The ratio in the Brass is almost zero due to no crystal rotation, while it changes slowly in the Goss. The study in Ref. [6] shows that the crystal orientation does not change after it reached stability, and in this case the plastic spin, or slip system activation, is the only deformation mechanism. The ratio in Fig.10 decreases quickly with increasing strain in the roCube, which

means the orientation rotates toward its stable position, and the role that plastic spin plays becomes dominant.

5. Conclusions

1. CPFÉ simulations of four single crystals have been conducted, and the predictions match well with the experimental observations.
2. Through-thickness deformation is inhomogeneous in the roCube, Goss, and Copper, and the different slip system activation, crystal rotation, and shear strain divide the thickness into matrix bands.
3. The shear strain distributes in the same manner as TD-rotation in the roCube and Goss, but in opposite direction, since the plastic spin is higher than crystal rotation. Crystal rotation being higher than plastic spin has been found in M1b of the Copper, and accordingly TD-rotation and shear strain are in the same direction.
4. Both crystal slip and crystal rotation develop in unstable orientations, and they compensate the material spin caused by each other, which thus lowers the redundant shear strain. The role of crystal slip becomes dominant when the orientations rotate toward stable positions.

Acknowledgements

The simulation was performed on the HPC cluster of the University of Wollongong.

References

- [1] H. Paul, J.H. Driver, Z. Jasiński, *Acta Mater.* **50**, 815 (2002).
- [2] N. Afrin, M.Z. Quadir, W. Xu, M. Ferry, *Acta Mater.* **60**, 6288 (2012).
- [3] Q. Liu, J. Wert, N. Hansen, *Acta Mater.* **48**, 4267 (2000).

- [4] H. Paul, J. Driver, C. Maurice, M. Miszczyk, D. Piot, Arch. Metall. Mater. **54**, 65 (2009).
- [5] K. Kashihara, H. Inagaki, Ceram. Trans. **201**, 453 (2008).
- [6] Z.J. Li, A. Godfrey, Q. Liu, Acta Mater. **52**, 149 (2004).
- [7] M. Wrobel, S. Dymek, M. Blicharski, S. Gorczyca, Mater. Res. Adv. Tech. **85**, 415 (1994).
- [8] Q. Liu, N. Hansen, Proc. Royal Soc. A **454**, 2555 (1998).
- [9] J.A. Wert, Acta Mater. **50**, 3125 (2002).
- [10] P. Van Houtte, S. Li, M. Seefeldt, L. Delannay, Int. J. Plast. **21**, 589 (2005).
- [11] H.R. Wenk, P. Van Houtte, Rep. Prog. Phys. **67**, 1367 (2004).
- [12] C. Lu, G.Y. Deng, A.K. Tieu, L.H. Su, H.T. Zhu, X.H. Liu, Acta Mater. **59**, 3581 (2011).
- [13] C. Zhang, L.W. Zhang, W.F. Shen, Y.N. Xia, Y.T. Yan, Acta Metall. Sin. (Engl. Lett.) **30**, 79 (2017).
- [14] F. Roters, P. Eisenlohr, L. Hantcherli, D.D. Tjahjanto, T.R. Bieler, D. Raabe, Acta Mater. **58**, 1152 (2010).
- [15] F. Roters, P. Eisenlohr, T.R. Bieler, D. Raabe, (Wiley-VCH Verlag GmbH & Co, 2010), p. 8.
- [16] K. Kashihara, Y. Tsujimoto, D. Terada, N. Tsuji, Mater. Charact. **75**, 129 (2012).
- [17] T. Inoue, N. Tsuji, Comput. Mater. Sci. **46**, 261(2009).
- [18] A. Albou, J.H. Driver, C. Maurice, Acta Mater. **58**, 3022 (2010).
- [19] R.J. Asaro, J. App. Mech. **50**, 921 (1983).
- [20] R.J. Asaro, A. Needleman, Acta Metall. **33**, 923 (1985).
- [21] T.-Y. Wu, J. L.Bassani, C. Laird, Pro. Royal Soc. A **435**, 20 (1991).
- [22] J. L.Bassani, T.-Y. Wu, Pro. Royal Soc. A **435**, 21 (1991).
- [23] G. Lin, K.S. Havner, Int. J. Plast. **12**, 695 (1996).
- [24] P. Franciosi, M. Berveiller, A. Zaoui, Acta Metall. **28**, 273 (1980).
- [25] Q. Liu, C. Maurice, J. Driver, N. Hansen, Metall. Mater. Trans. A **29**, 2333 (1998).
- [26] D. Guanyu, Dissertation, University of Wollongong, 2014.
- [27] L.Y. Si, C. Lu, N.N. Huynh, A.K. Tieu, X.H. Liu, J. Mater. Proc. Tech. **201**, 79 (2008).
- [28] P. Wei, C. Lu, H. Liu, L. Su, G. Deng, K. Tieu, Crystals **7**, 12 (2017).
- [29] A. Godfrey, D. Juul Jensen, N. Hansen, Acta Mater. **46**, 835 (1998).
- [30] R.Y. Liang, P. Yang, W.M. Mao, Acta Metall. Sin. (Engl. Lett.) **30**, 895 (2017).
- [31] Z.S. Zhu, N.P. Chen, J.L. Gu, M.G. Yan, Acta Metall. Sin. Ser. A **9**, 601 (1996).
- [32] S. Li, F. Sun, H. Li, Acta Mater. **58**, 1317 (2010).
- [33] C.S. Lee, B.J. Duggan, Metall. Trans. A **22**, 2637 (1991).
- [34] J.X. Li, X.H. Liu, G.D. Wang, Acta Metall. Sin. (Engl. Lett.) **15**, 312 (2002).